

SPECIFICATION

DEVICE NAME : SILICON DIODE

TYPE NAME : ERW03-060

SPEC. No. :

DATE :

Fuji Electric Co.,Ltd.

This Specification is subject to change without notice.

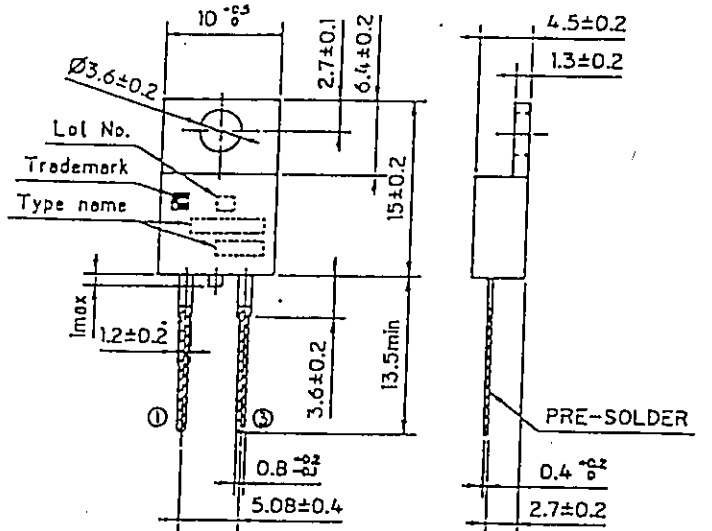
	DATE	NAME	APPROVED	Fuji Electric Co.,Ltd.	
DRAWN				DWG.NO.	1/6
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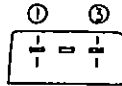
Ratings and characteristics of Fuji silicon diode

ERW03-060

1. Outline Drawing



DIMENSIONS ARE IN MILLIMETERS.

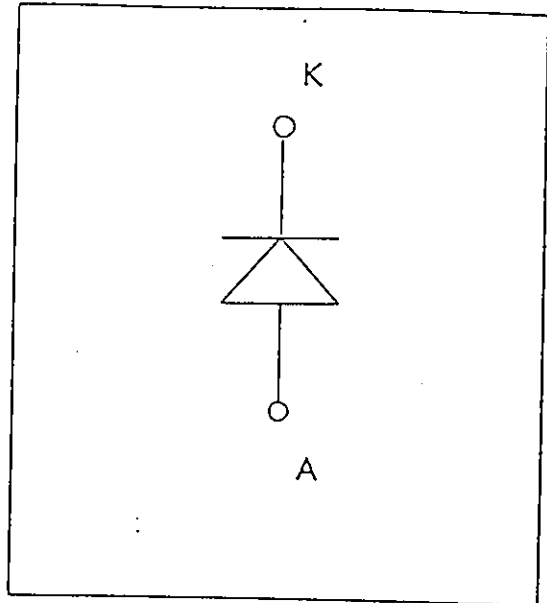


CONNECTION

- ① CATHODE
- ③ ANODE

JEDEC : TO-220AC

2. Equivalent circuit



3. Absolute maximum ratings (Tc=25°C)

Items	Symbols	Conditions	Ratings	Units
Repetitive Reverse Voltage	V_{RRM}	—————	600	V
Repetitive peak surge current	I_{FM}	20kHz Duty50% Squ. wave	Tc= 92°C 15	A
			Tc= 25°C 26	A
Average rectified forward current	$I_{F(AV)}$	D C	15	A
Non-repetitive peak surge current	I_{FSM}	Pulse10ms, sin wave.	80	A
Maximam Power Dissipaion	P_D	—————	45	W
Operating Temperature	T_j	—————	+150	°C
Storage Temperature	T_{stg}	—————	-40 ~+150	°C
Mounting Screw Torque	—————	—————	50	N · cm

4. Electrical Characteristics (at $T_c=25^{\circ}\text{C}$ unless otherwise specified)

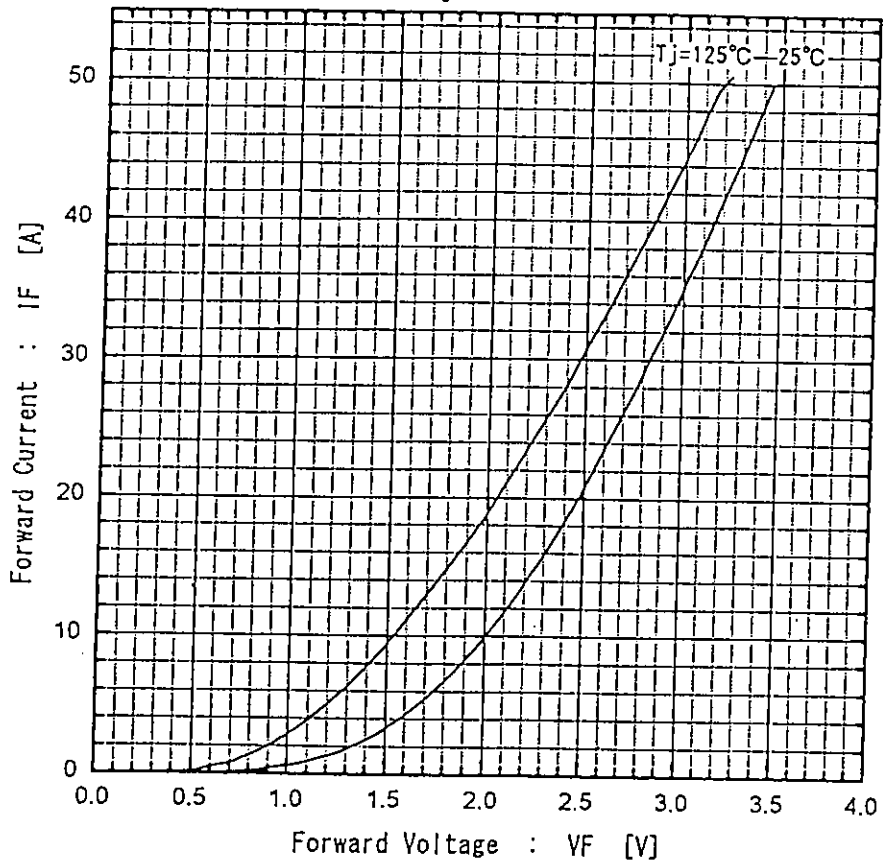
Items	Symbols	Characteristics			Conditions	Unit
		min.	typ.	max.		
Reverse Current	I_R	—	—	1.0	$V_R = 600 \text{ V}$	mA
forward voltage	VF	—	—	3.0	$I_F = 15\text{A}$	V
Reverse recovery time	t_{rr}	—	—	0.3	$I_F=15\text{A}, V_R=200\text{V}$ $di/dt=100\text{A}/\mu\text{s}$	μS

5. Thermal resistance characteristics

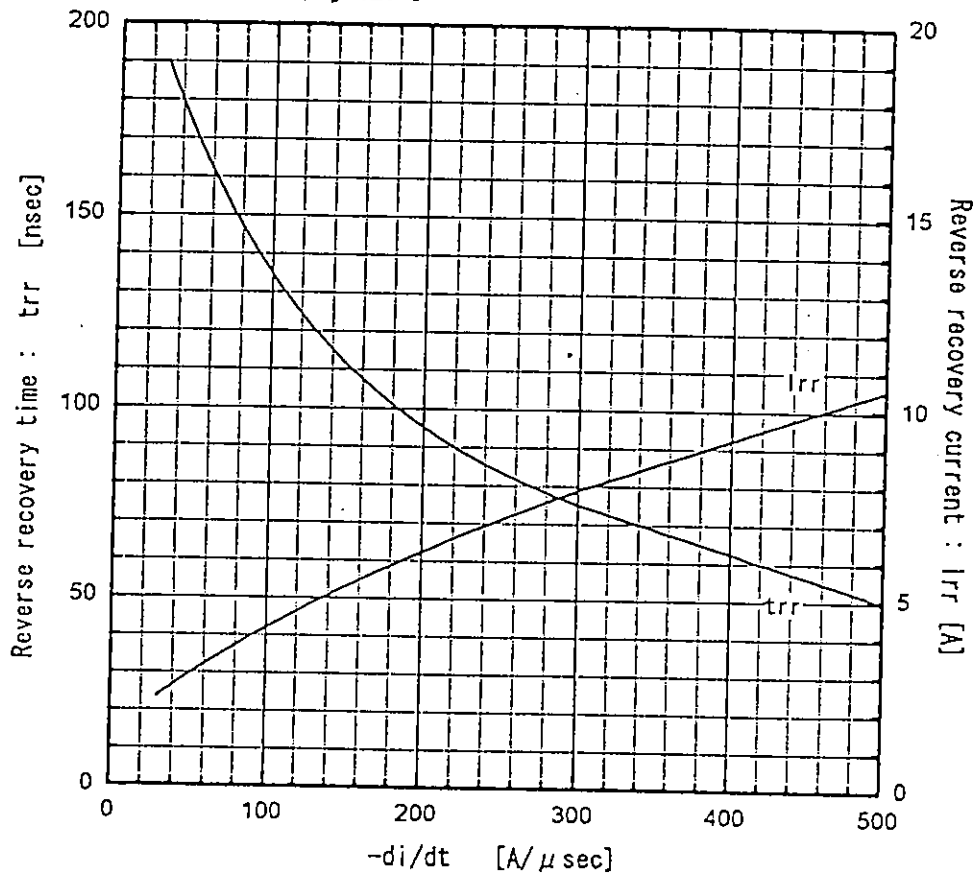
Items	Symbols	Characteristics			Conditions	Unit
		min.	typ.	max.		
Thermal resistance	$R_{th(j-c)}$	—	—	2.77	junction to case	$^{\circ}\text{C}/\text{W}$

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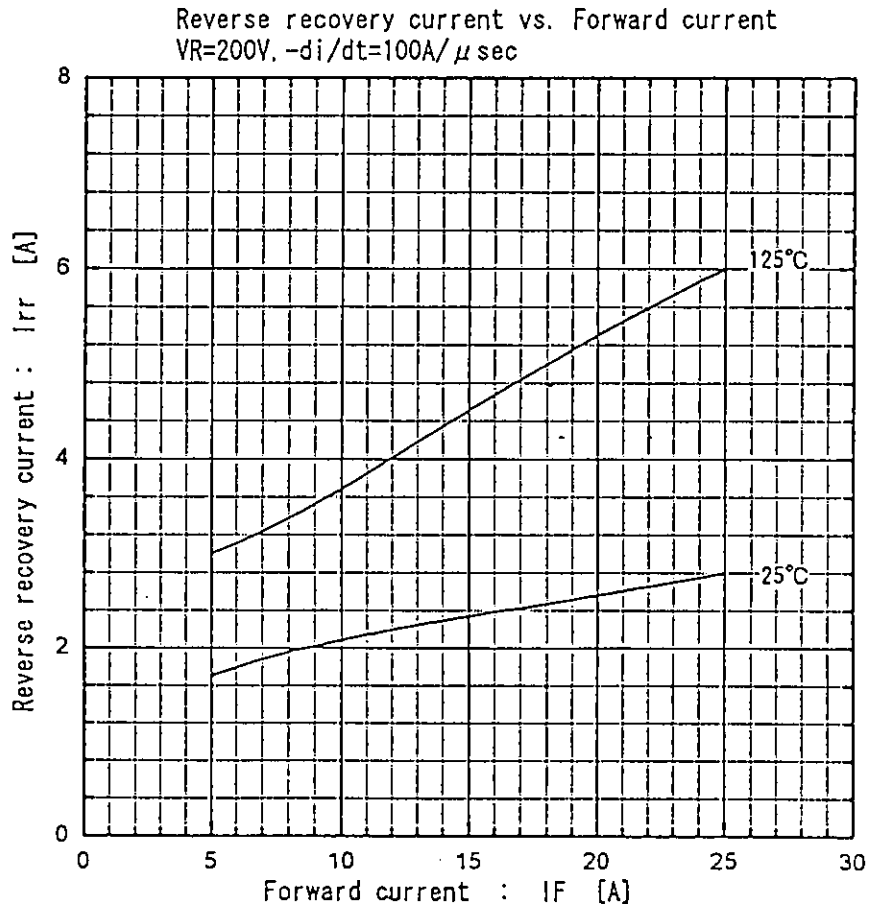
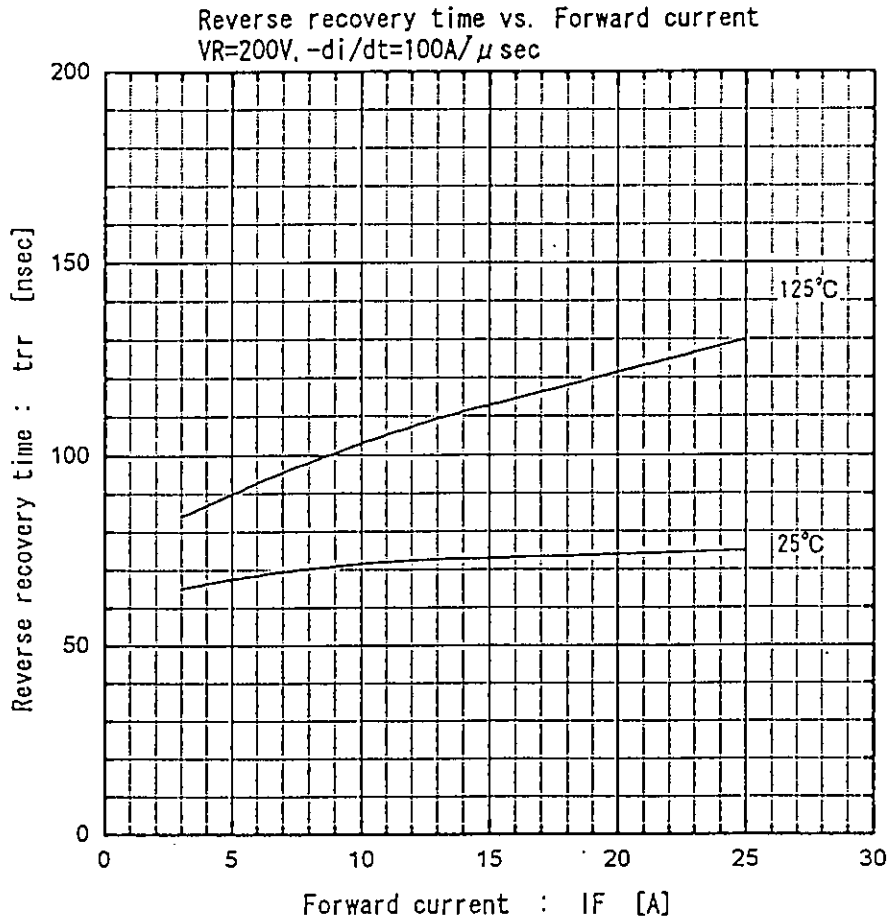
Forward voltage vs. Forward current



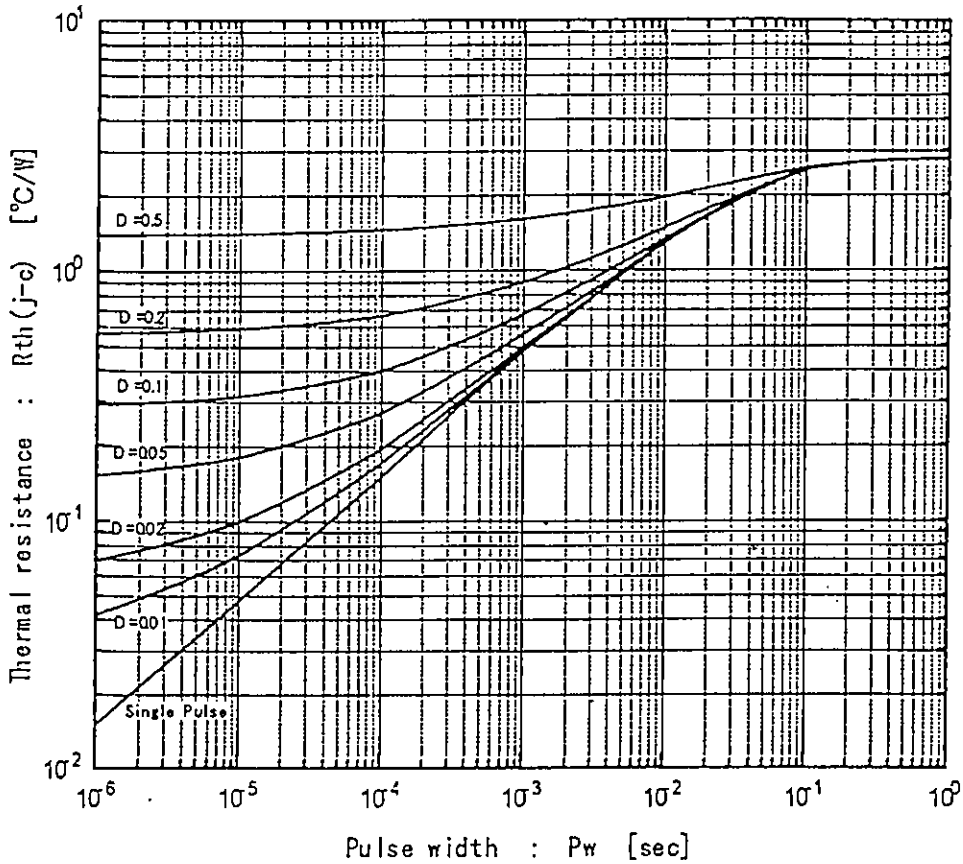
Reverse recovery characteristics vs. $-di/dt$
 $I_F=15A, T_J=125^\circ C$



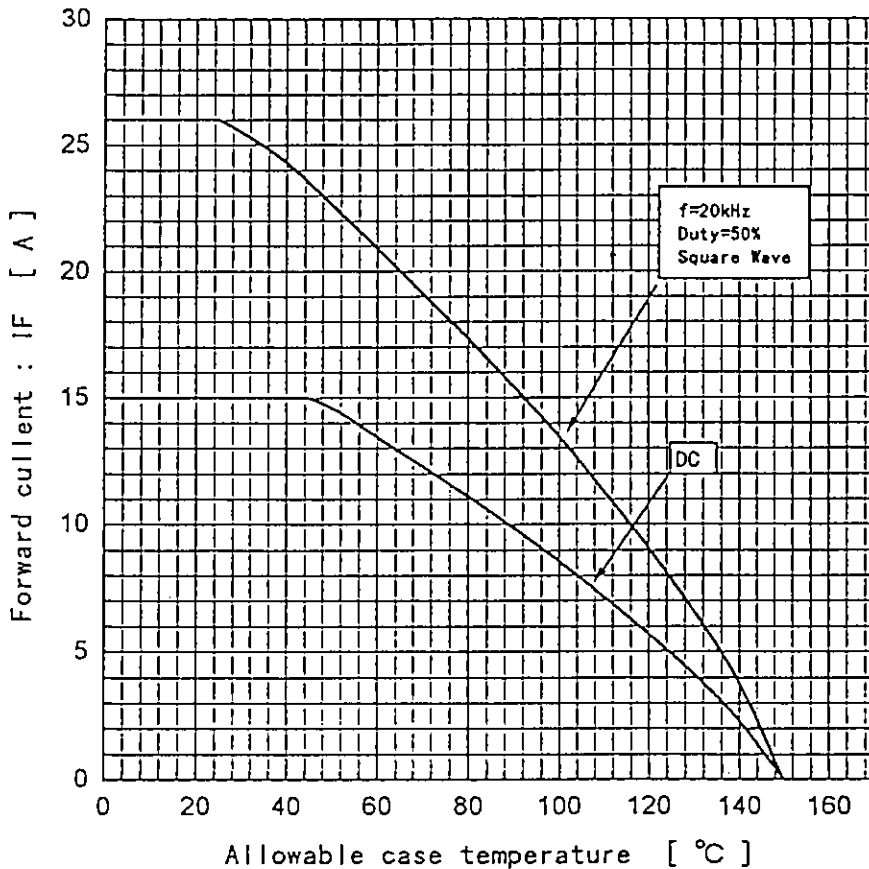
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Transient thermal resistance



Forward current vs. Max. allowable case temperature



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